NSN 5961-01-123-2992

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View Online at https://aerobasegroup.com/nsn/5961-01-123-2992 **Inclosure Material:** Metal **Overall Length:** 0.550 inches **End Application:** Generator 76301 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 nonrepetitive peak reverse voltage and 400.0 nonrepetitive peak off-state voltage **Current Rating Per Characteristic:** 150.00 amperes forward current, total rms watts **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 89954-144a9641 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug

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N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

No

Fiig:

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